

Description

The AU0521P0 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The AU0521P0 complies with the IEC 61000-4-2 (ESD) with ±30kV air and ±30kV contact discharge. It is assembled into an ultra-small 0.6x0.3x0.3mm lead-free DFN package. The ultra small size and high ESD surge protection make AU0521P0 an ideal choice to replace 0201 size multilayer varistors (MLVs) and protect cell phone, digital cameras, audio players and many other portable applications.

Features

- Ultra small package: 0.6x0.3x0.3mm
- Very low capacitance
- Protects one data or power line
- Ultra low leakage: nA level
- Operating voltage: 5V
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 Air discharge: ±30kV
 Contact discharge: ±30kV
 - IEC61000-4-5 (Lightning) 8A (8/20µs)
- RoHS Compliant

Mechanical Characteristics

- Package: DFN0603-2 (0.6×0.3×0.3mm)
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

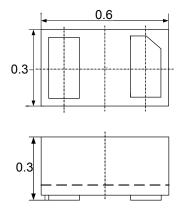
- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- Audio Players
- Keypads, Side Keys, USB 2.0, LCD Displays

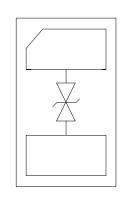
Marking Information



5A = Device Marking Code

Dimensions and Pin Configuration





Package Dimensions

Circuit and Pin Schematic

Ordering Information

Part Number	Packaging	Reel Size
AU0521P0	10000/Tape & Reel	7 inch



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

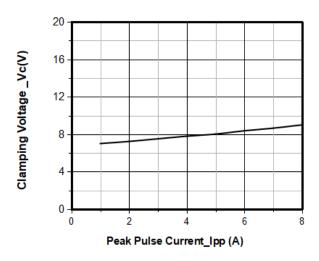
Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20µs)	Ppk	80	W	
Peak Pulse Current (8/20µs)	Ірр	8	А	
ESD per IEC 61000-4-2 (Air)	1/505	±30	1.37	
ESD per IEC 61000-4-2 (Contact)	VESD	±30	kV	
Operating Temperature Range	TJ	−55 to +125	°C	
Storage Temperature Range	Tstg	-55 to +150	°C	

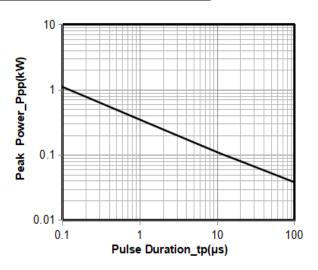
Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Breakdown Voltage	VBR	6		9	V	IT = 1mA
Reverse Leakage Current	I _R			0.1	μA	VRWM = 5V
Clamping Voltage	Vc			8	V	IPP = 1A (8 x 20μs pulse)
Clamping Voltage	Vc			10	V	IPP = 8A (8 x 20µs pulse)
Junction Capacitance	Cl			20	pF	VR = 0V, f = 1MHz

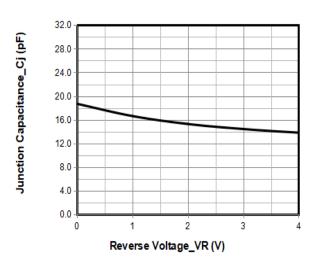


Typical Performance Characteristics (TA=25°C unless otherwise Specified)

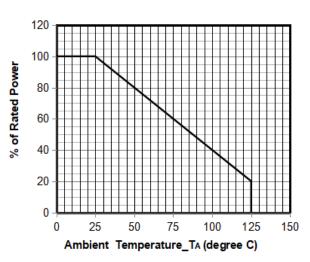




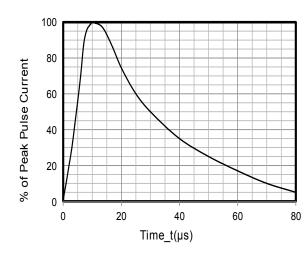
Junction Capacitance vs. Reverse Voltage



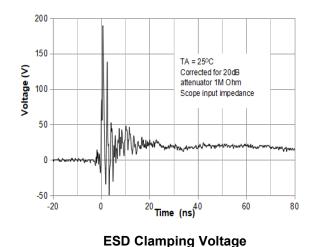
Peak Pulse Power vs. Pulse Time



Clamping Voltage vs. Peak Pulse Current



Power Derating Curve

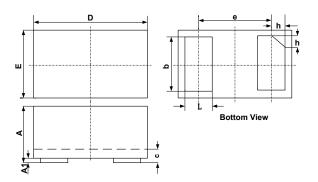


8 X 20µs Pulse Waveform

8 kV Contact per IEC61000-4-2

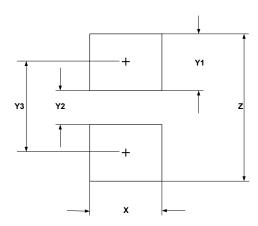


DFN0603-2 Package Outline Drawing



	DIMENSIONS		
2).71	MILLIMETERS		
SYM	MIN	NOM	MAX
Α	0.230		0.330
A1	0.000	0.020	0.050
b	0.215	0.245	0.275
С	0.120	0.150	0.180
D	0.550	0.600	0.650
е		0.355 BSC)
Е	0.250	0.300	0.350
L	0.160	0.190	0.220
h	0.079 BSC		

Suggested Land Pattern



SYM	DIMENSIONS		
	MILLIMETERS	INCHES	
Х	0.30	0.012	
Y1	0.25	0.010	
Y2	0.15	0.006	
Y3	0.40	0.016	
Z	0.65	0.026	

Contact Information

Applied Power Microelectronics Co., Ltd.

Website: http://www.appliedpowermicro.com

Email: sales@appliedpowermicro.com

Phone: +86 (0519) 8399 3606

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